

Vishay Siliconix

N-Channel 12-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)	
	0.020 at V _{GS} = 4.5 V	9		
12	0.024 at V _{GS} = 2.5 V	9	7.5 nC	
	0.029 at V _{GS} = 1.8 V	9		

PowerPAK SC-75-6L-Single

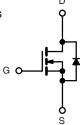
1 60 mm 1.60 mm

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- New Thermally Enhanced PowerPAK® SC-75 Package
- Small Footprint Area
- Low On-Resistance
- 100 % R_g Tested Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Load Switch, PA Switch and Battery Switch for Portable Devices
- High Frequency dc-to-dc Converters



Ordering Information: SiB488DK-T1-GE3 (Lead (Pb)-free and Halogen-free)

Lot Traceability and Date code

Marking Code A G X

ХХХ

Part # code

N-Channel MOSFET

Parameter Drain-Source Voltage Gate-Source Voltage		Symbol	Limit	Unit V	
		V _{DS}	12		
		V _{GS}	± 8		
Continuous Drain Current (T _{.1} = 150 °C)	T _C = 25 °C T _C = 70 °C	I _D	9 ^a 9 ^a		
	T _A = 25 °C T _A = 70 °C		9 ^{b, c} 7.2 ^{b, c}	A	
Pulsed Drain Current		I _{DM}	35		
Continuous Source-Drain Diode Current	T _C = 25 °C T _A = 25 °C	I _S	9 ^a 2 ^{b, c}		
Maximum Power Dissipation	$T_{C} = 25 °C$ $T_{C} = 70 °C$ $T_{A} = 25 °C$	P _D	13 8.4 2.4 ^{b, c}	w	
$T_A = 70 \text{ °C}$ Operating Junction and Storage Temperature Range		T _J , T _{stg}	1.6 ^{b, c} - 55 to 150		
Soldering Recommendations (Peak Temperature		260			

THERMAL RECIGIANCE RATINGS

I RENMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^{b, f}	t ≤ 5 s	R _{thJA}	41	51	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	7.5	9.5		

Notes:

a. $T_C = 25 \ ^{\circ}C$, package limited.

b. Surface mounted on 1" x 1" FR4 board.

c. t = 5 s.

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

f. Maximum under steady state conditions is 105 °C/W.

Document Number: 65668 S10-0045-Rev. A, 11-Jan-10 www.vishay.com 1



COMPLIANT

HALOGEN

FREE

d. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SC-75 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.



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Symbol V _{DS} V _{DS} /T _J V _{GS} (th)/T _J V _{GS} (th) I _{DSS} I _D I _D (on) R _{DS} (on) g _{fs}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$ $I_{D} = 250 \mu\text{A}$ $V_{DS} = V_{GS}, \text{ I}_{D} = 250 \mu\text{A}$ $V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{V}$ $V_{DS} = 12 \text{V}, V_{GS} = 0 \text{V}$ $V_{DS} = 12 \text{V}, V_{GS} = 0 \text{V}, T_{J} = 55 ^{\circ}\text{C}$ $V_{DS} \ge 5 \text{V}, V_{GS} = 4.5 \text{V}$ $V_{GS} = 4.5 \text{V}, I_{D} = 6.3 \text{A}$ $V_{GS} = 2.5 \text{V}, I_{D} = 5.8 \text{A}$	12 0.4 15	Typ. 11 - 2.7	1.0 ± 100 1	V mV/°C V nA	
V _{DS} /T _J / _{GS(th)} /T _J V _{GS(th)} I _{GSS} I _{DSS} I _{D(on)} R _{DS(on)}	$I_{D} = 250 \ \mu\text{A}$ $V_{DS} = V_{GS}, I_{D} = 250 \ \mu\text{A}$ $V_{DS} = 0 \ V, V_{GS} = \pm 8 \ V$ $V_{DS} = 12 \ V, V_{GS} = 0 \ V$ $V_{DS} = 12 \ V, V_{GS} = 0 \ V, T_{J} = 55 \ ^{\circ}\text{C}$ $V_{DS} \ge 5 \ V, V_{GS} = 4.5 \ V$ $V_{GS} = 4.5 \ V, I_{D} = 6.3 \ \text{A}$	0.4		± 100	mV/°C V nA	
V _{DS} /T _J / _{GS(th)} /T _J V _{GS(th)} I _{GSS} I _{DSS} I _{D(on)} R _{DS(on)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$ $V_{DS} = 0 \ V, V_{GS} = \pm 8 \ V$ $V_{DS} = 12 \ V, V_{GS} = 0 \ V$ $V_{DS} = 12 \ V, V_{GS} = 0 \ V, T_J = 55 \ ^{\circ}C$ $V_{DS} \ge 5 \ V, V_{GS} = 4.5 \ V$ $V_{GS} = 4.5 \ V, I_D = 6.3 \ A$			± 100	V nA	
V _{GS(th)} I _{GSS} I _{DSS} I _{D(on)} R _{DS(on)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$ $V_{DS} = 0 \ V, V_{GS} = \pm 8 \ V$ $V_{DS} = 12 \ V, V_{GS} = 0 \ V$ $V_{DS} = 12 \ V, V_{GS} = 0 \ V, T_J = 55 \ ^{\circ}C$ $V_{DS} \ge 5 \ V, V_{GS} = 4.5 \ V$ $V_{GS} = 4.5 \ V, I_D = 6.3 \ A$		- 2.7	± 100	V nA	
V _{GS(th)} I _{GSS} I _{DSS} I _{D(on)} R _{DS(on)}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$ $V_{DS} = 12 V, V_{GS} = 0 V$ $V_{DS} = 12 V, V_{GS} = 0 V, T_{J} = 55 °C$ $V_{DS} \ge 5 V, V_{GS} = 4.5 V$ $V_{GS} = 4.5 V, I_{D} = 6.3 A$			± 100	nA	
I _{GSS} I _{DSS} I _{D(on)} R _{DS(on)}	$V_{DS} = 12 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 12 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55 \text{ °C}$ $V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$ $V_{GS} = 4.5 \text{ V}, I_D = 6.3 \text{ A}$	15		1		
I _{DSS} I _{D(on)} R _{DS(on)}	$V_{DS} = 12 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 \text{ °C}$ $V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V}$ $V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 6.3 \text{ A}$	15				
I _{D(on)} R _{DS(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$ $V_{GS} = 4.5 \text{ V}, I_D = 6.3 \text{ A}$	15		10		
R _{DS(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$ $V_{GS} = 4.5 \text{ V}, I_D = 6.3 \text{ A}$	15		10	μA	
R _{DS(on)}	60 5				A	
	$V_{GS} = 2.5 \text{ V}, I_D = 5.8 \text{ A}$		0.016	0.020	-	
			0.019	0.024	Ω	
9 _{fs}	$V_{GS} = 1.8 \text{ V}, I_D = 2.5 \text{ A}$		0.023	0.029		
	$V_{\rm DS} = 10 \text{ V}, \text{ I}_{\rm D} = 6.3 \text{ A}$		32		S	
015						
C _{iss}			725			
C _{oss}	V _{DS} = 6 V, V _{GS} = 0 V, f = 1 MHz		195		pF	
	$v_{\rm DS} = 0 v, v_{\rm GS} = 0 v, t = 1 0012$		90			
C _{rss}	V _{DS} = 6 V, V _{GS} = 8 V, I _D = 9 A		90 13.1	20		
Qg	$v_{DS} = 6 v, v_{GS} = 8 v, I_D = 9 A$		7.5	12	nC	
Q _{gs}	V _{DS} = 6 V, V _{GS} = 4.5 V, I _D = 9 A		1.1	12		
Q _{gd}	DS = 0 V , $VGS = 1.0$ V , $D = 0$ V		0.8			
-	f – 1 MHz	0.5		5	Ω	
•	1 - 1 10112	0.5		-	22	
	V		-	-	- ns	
			-	-		
. ,	$D = T = T$, $G \in \mathbb{R}$		-			
			-	-		
			-	-		
			-	-		
()	$D = 7.27$, $V_{GEN} = 0.0$, $R_{g} = 1.22$					
Ч			10	15		
	T ₂ = 25 °C		T	0	T	
	16-25 0				A	
	$l_{0} = 72$ Å $V_{} = 0.4$		0.9		V	
	'S - 7.2 m, VGS - V V					
	/				ns	
	I_F = 7.2 A, dI/dt = 100 A/µs, T_J = 25 $^\circ C$			Ö	nC	
					ns	
	Rg td(on) tr td(off) tf td(on) tr td(off) tr lg Vg lg trr Qrr ta tb	$\begin{array}{c c} t_{d(on)} & & \\ \hline t_{d(off)} & & \\ \hline t_{d(off)} & & \\ \hline t_{f} & & \\ \hline t_{d(on)} & & \\ \hline t_{f} & & \\ \hline t_{d(on)} & & \\ \hline t_{r} & & \\ \hline t_{d(off)} & & \\ \hline t_{d} & & \\ \hline t_{d(off)} & & \\ \hline t_{f} & & \\ \hline \hline t_{f} & & \\ \hline \hline & & \\ \hline \hline & & \\ \hline \hline & & \\ \hline & & \\ \hline \hline \\ \hline & & \\ \hline \hline \\ \hline & & \\ \hline \hline \hline \hline \hline \\ \hline \hline \hline \hline \hline \\ \hline \hline \hline \hline \hline \hline \hline \\ \hline \hline$	$\begin{array}{c c} t_{d(on)} & & & \\ \hline t_{d(off)} & & \\ \hline t_{f} & & \\ \hline t_{d(off)} & & \\ \hline t_{f} & & \\ \hline t_{f} & & \\ \hline t_{d(on)} & & \\ \hline t_{r} & & \\ \hline t_{d(off)} & & \\ \hline t_{r} & & \\ \hline t_{D} \cong 7.2 \text{ A}, \text{ V}_{GEN} = 4.5 \text{ V}, \text{ R}_{g} = 1 \Omega & \\ \hline & & \\ \hline t_{d(off)} & & \\ \hline t_{D} \cong 7.2 \text{ A}, \text{ V}_{GEN} = 8 \text{ V}, \text{ R}_{g} = 1 \Omega & \\ \hline & & \\ \hline t_{f} & & \\ \hline & & \\ \hline \hline & & \\ \hline \hline \\ \hline \hline & & \\ \hline \hline \\ \hline \hline \\ \hline \hline & & \\ \hline \hline \hline \\ \hline \hline \hline \\ \hline \hline \hline \hline$	$\begin{array}{c c} t_{d(on)} \\ \hline t_{d(off)} \\ \hline t_{f} \\ \hline t_{g} \\ \hline t_{f} \\ \hline t_{g} \\ \hline t_{f} \\ \hline t_{g} \\ t_{g} \\ \hline t_{g} \\ t_{g} \\ t_{g} \\ t_{g} \\ t_{g} \\ \hline t_{g} \\ t_$	$\begin{array}{c c c c c c c c c } \hline t_{d(on)} \\ \hline t_r \\ \hline t_r \\ \hline t_{d(off)} \\ \hline t_f \\ \hline$	

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

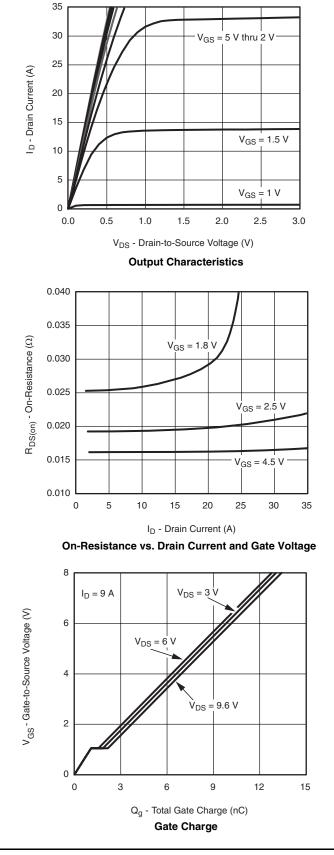
b. Guaranteed by design, not subject to production testing.

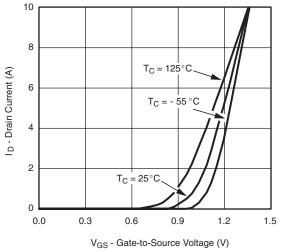
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



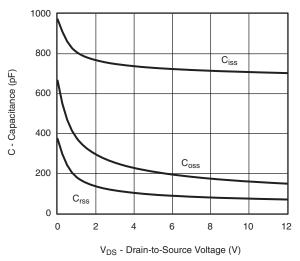
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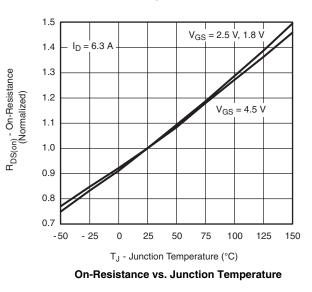




Transfer Characteristics



Capacitance

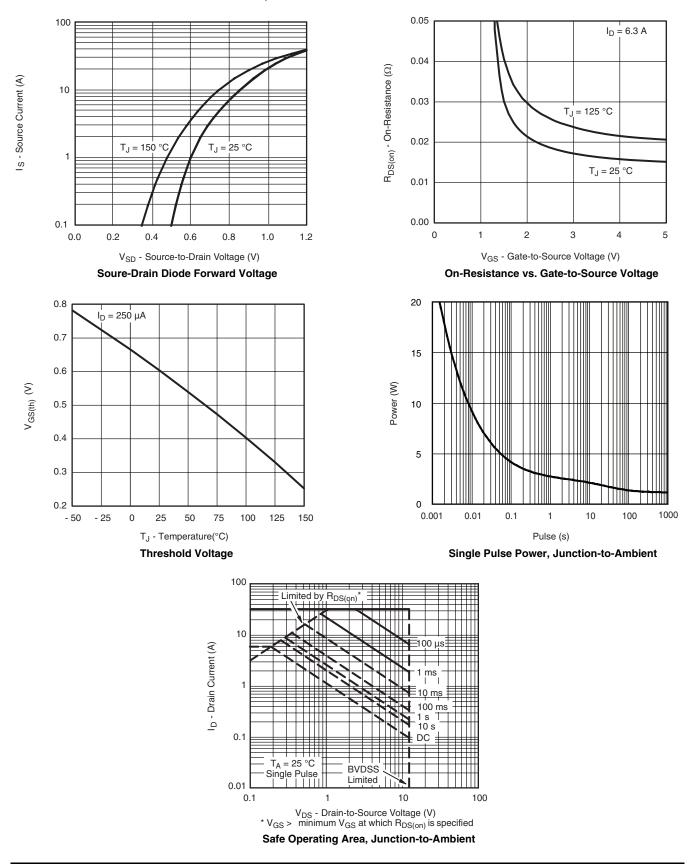


Document Number: 65668 S10-0045-Rev. A, 11-Jan-10

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



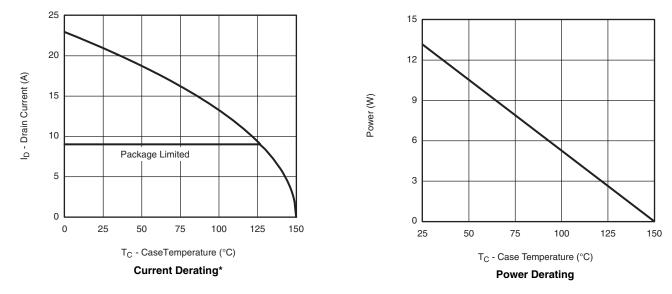
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

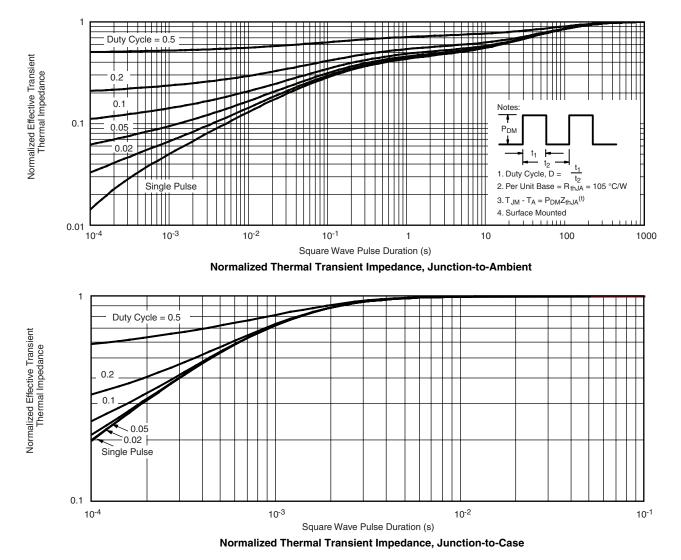


* The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65668.

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